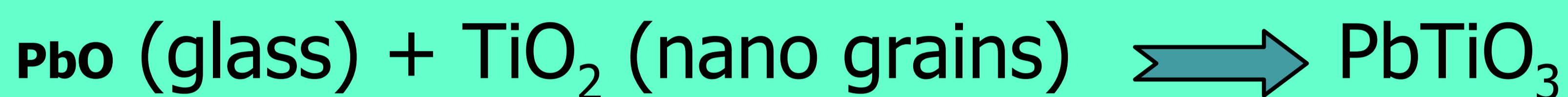


Low-temperature thick-film dielectrics stabilised by reaction with a nanocrystalline powder

Caroline Jacq, Thomas Maeder, Sonia Vionnet and Peter Ryser,
Laboratoire de Production Microtechnique, (IPR-LPM), EPFL
Ecole Polytechnique Fédérale de Lausanne, CH-1015 Lausanne

Aim of this project: to develop dielectrics for a low-temperature thick-film system for substrates such as steel, titanium, aluminum and glass.

Stabilisation of a glass by controlled reaction with a nanograin powder :



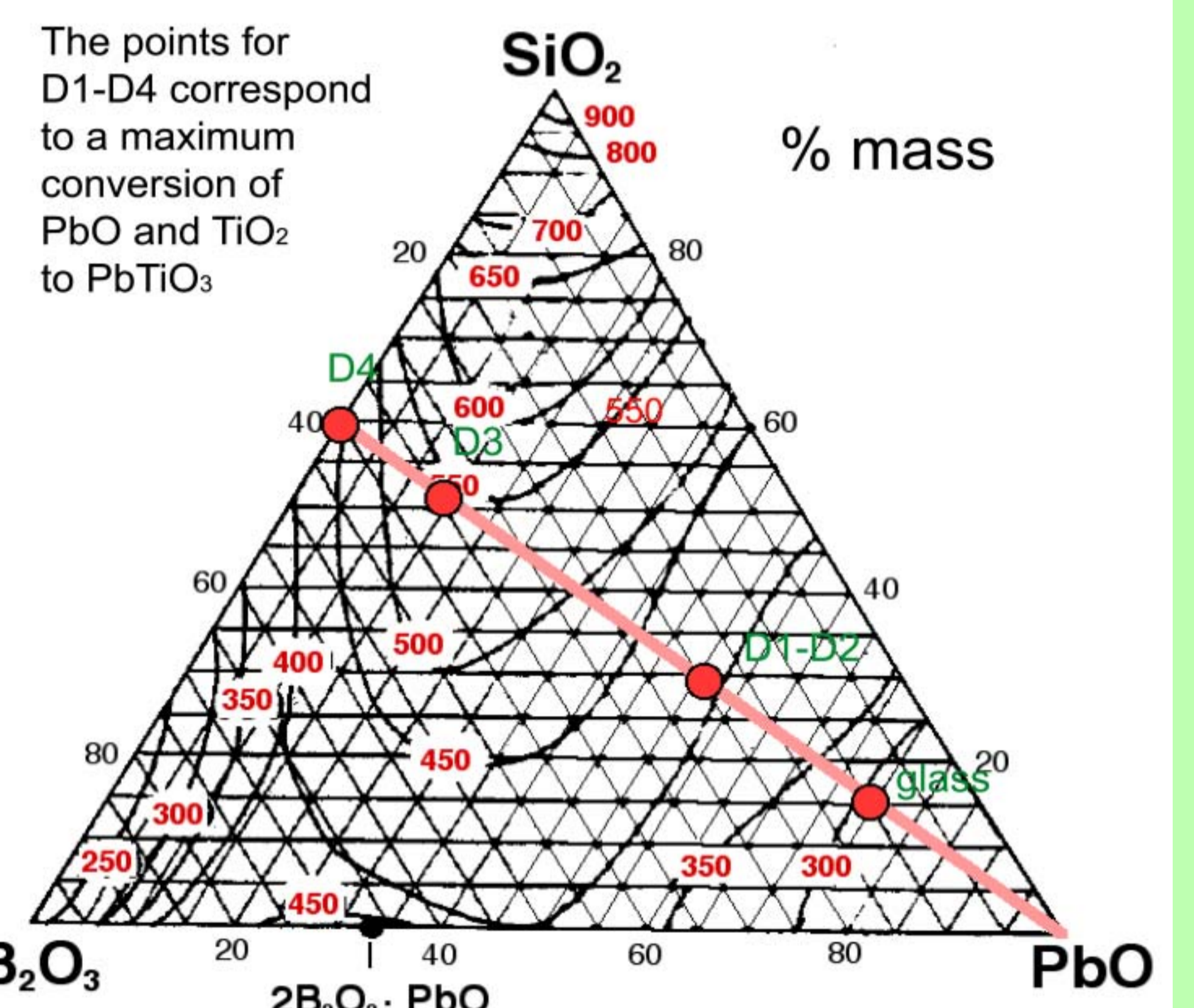
Stabilisation by **Pb depletion in glass** and **increase in filler volume**

Preparation of pastes: TiO₂ powder have been mixed with glass with different proportions. Two TiO₂ powders with different grain diameter have been used. The powder with coarse grains contain only rutile, stable phase of TiO₂.

On the contrary the powder with finer grains contains anatase which turn into rutile at high temperature.

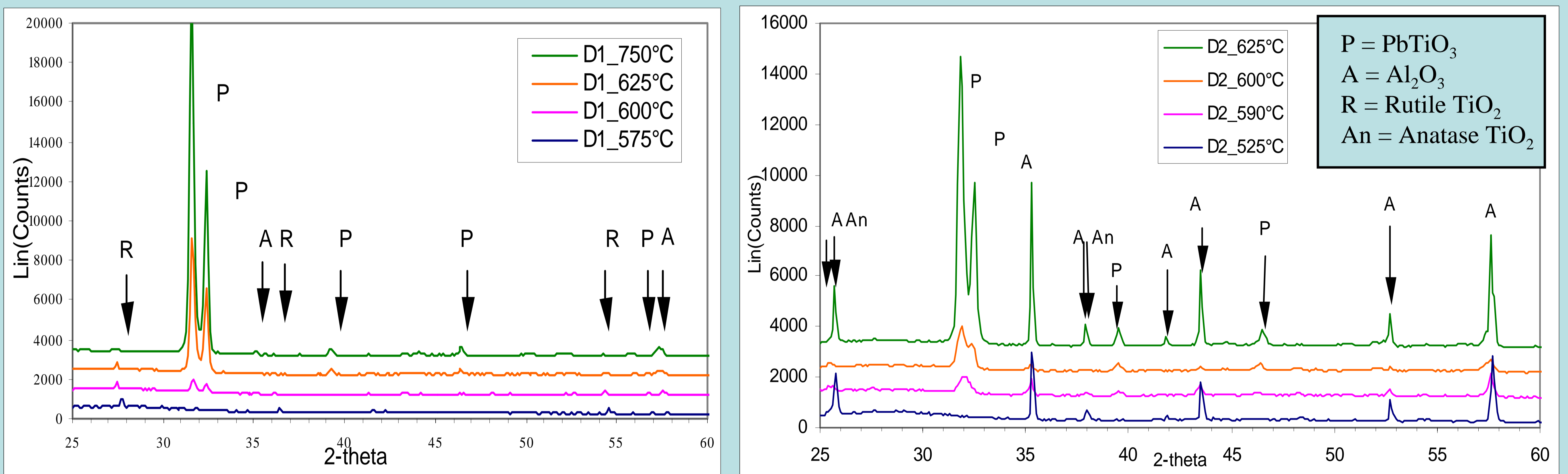
	TiO ₂ grain diameter	Fraction Ti/Pb
D1	5 μm	0.63
D2	21nm	0.63
D3	21nm	0.95
D4	21nm	1.33

Pb depletion in glass



Depletion of PbO results in an increase of stability.
(Diagram after Trubnikov, 2000)

X-ray Spectra of D1 and D2 pastes fired at different temperatures



X-ray characterisation allows to examine at which temperature PbTiO₃ peaks appear and rutile and anatase peaks disappear. The crystallisation takes place 20°C lower with the nanograin TiO₂ powder (D2) than with the coarse-grained one (D1).

Conversion level of TiO₂ to PbTiO₃

100% of the TiO₂ has reacted with the PbO contained in glass for D1 and D2 pastes, in accordance with the stoichiometry. For D3, only 70% of PbTiO₃ has been measured (instead of 100%), due to kinetic limitations. 50-60% of PbTiO₃ has been obtained with D4, which contains more TiO₂ than PbO. Moreover, the figure 1 confirms that the crystallisation takes place 20°C lower with D2 than D1.

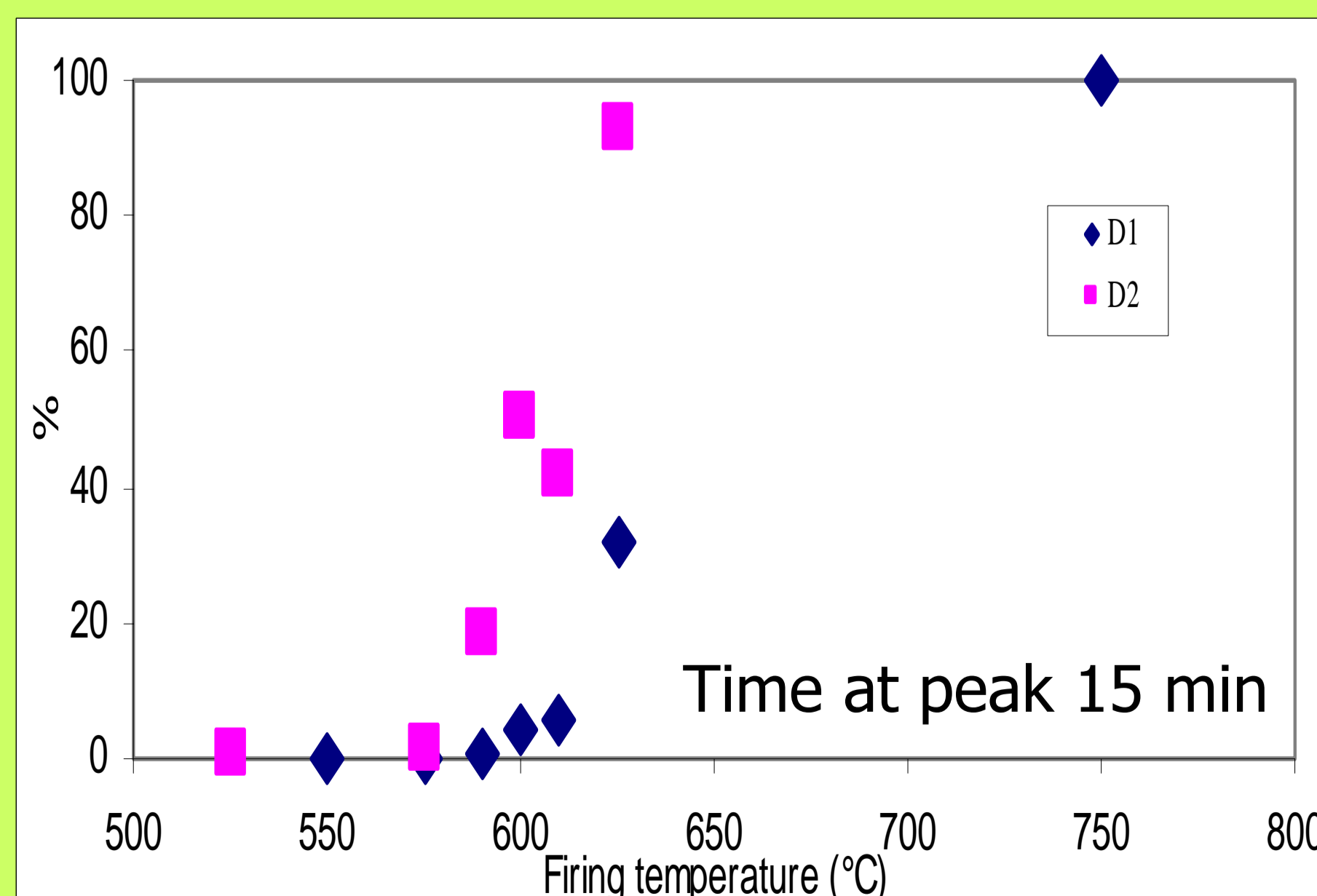


Figure 1

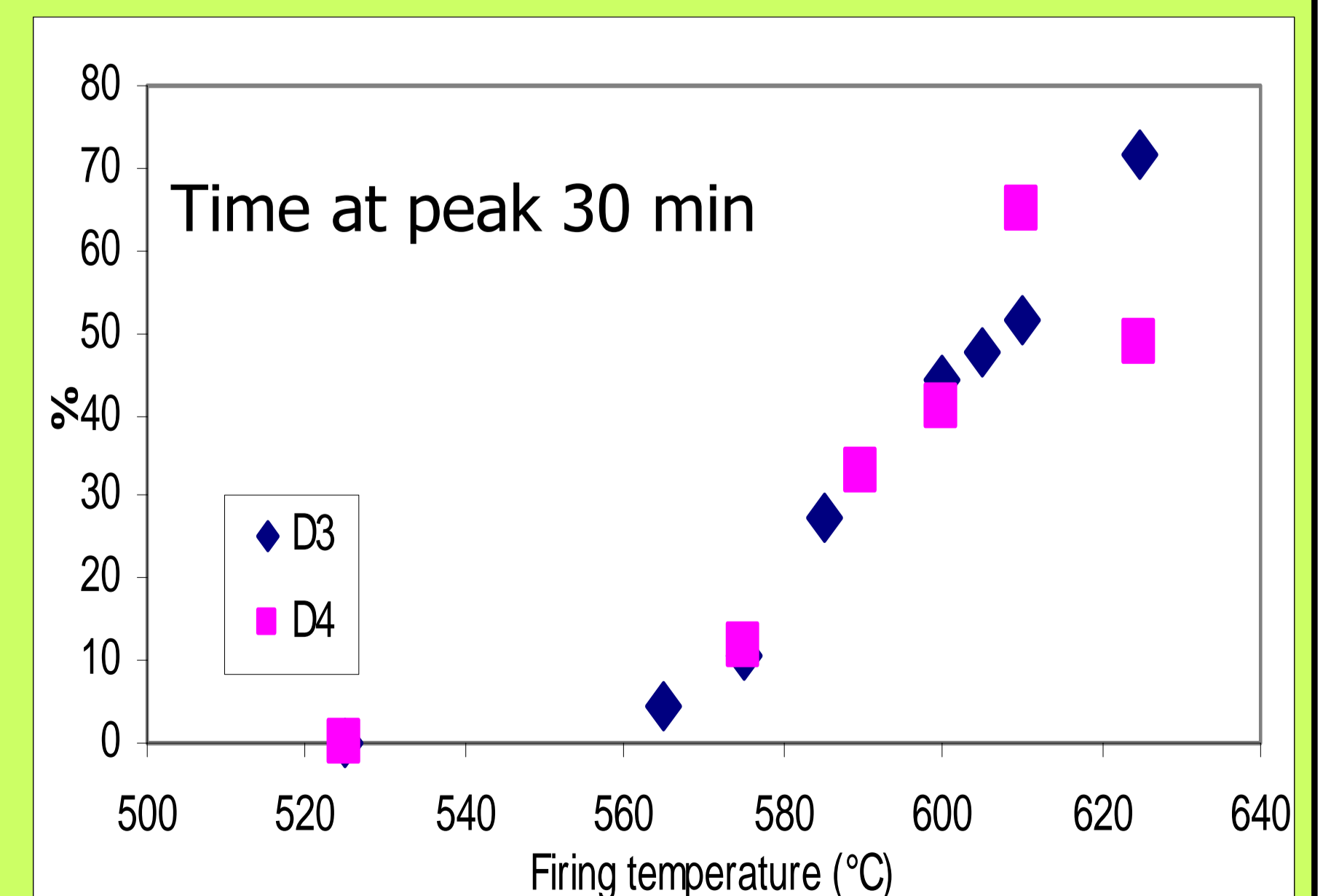


Figure 2